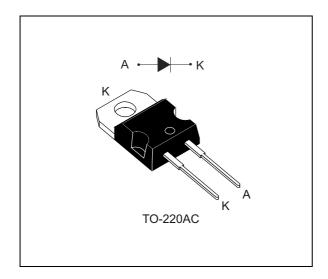


STPSC6C065-Y

Automotive 650 V power Schottky silicon carbide diode

Datasheet - production data



Features

- AEC-Q101 qualified
- No or negligible reverse recovery
- Switching behavior independent of temperature
- Dedicated to PFC applications
- High forward surge capability
- PPAP capable
- ECOPACK®2 compliant component

Description

The SiC diode is an ultrahigh performance power Schottky diode. It is manufactured using a silicon carbide substrate. The wide band gap material allows the design of a Schottky diode structure with a 650 V rating. Due to the Schottky construction, no recovery is shown at turn-off and ringing patterns are negligible. The minimal capacitive turn-off behavior is independent of temperature and is ideal for automotive applications.

Especially suited for use as boost diode, this rectifier will enhance the performance in hard switching conditions. Its high forward surge capability ensures a good robustness during transient phases.

Table 1. Device summary

Symbol	Value
I _{F(AV)}	6 A
V_{RRM}	650 V
T _j (max)	175 °C

Characteristics STPSC6C065-Y

1 Characteristics

Table 2. Absolute ratings (limiting values at 25 °C unless otherwise specified)

Symbol	Par	Value	Unit	
V_{RRM}	Repetitive peak reverse voltage, T _j = -40 °C		650	V
I _{F(RMS)}	Forward rms current		22	Α
I _{F(AV)}	Average forward current	$T_{c} = 135 {}^{\circ}C^{(1)}, DC$	6	Α
I _{FSM}	Surge non repetitive forward current		49 43 375	A
I _{FRM}	Repetitive peak forward current $T_c = 135 ^{\circ}C^{(1)}, T_j = 175 ^{\circ}C, \delta = 0.1$		25	Α
T _{stg}	Storage temperature range		-65 to +175	°C
T _j	Operating junction temperature	-40 to +175	°C	

^{1.} Value based on $R_{th(j-c)}$ max.

Table 3. Thermal resistance

Symbol	Parameter	Val	Unit	
Syllibol	raiametei	Тур.	Max.	Oilit
R _{th(j-c)}	Junction to case	1.95	2.6	°C/W

Table 4. Static electrical characteristics

Symbol	Parameter	Tests conditions		Min.	Тур.	Max.	Unit
I _R ⁽¹⁾ Reverse leakage current	T _j = 25 °C	V - V	-	5	60	μΑ	
'R`´	ig . A neverse leakage current	T _j = 150 °C	$V_R = V_{RRM}$	-	50	250	μΛ
V _E (2)	V _F ⁽²⁾ Forward voltage drop	T _j = 25 °C	I _F = 6 A	i	1.56	1.75	V
v F · · · · · · · · · · · · · · · · · ·	Torward vollage drop	T _j = 150 °C	IF = 0 A	-	1.98	2.5	V

^{1.} $t_p = 10 \text{ ms}, \delta < 2\%$

To evaluate the conduction losses use the following equation:

$$P = 1.35 \times I_{F(AV)} + 0.192 \times I_{F^{2}(RMS)}$$

^{2.} $t_p = 500 \ \mu s, \ \delta < 2\%$

STPSC6C065-Y Characteristics

Table 5. Dynamic electrical characteristics

Symbol	Parameter Test conditions		Тур.	Unit
Q _{cj} ⁽¹⁾	Total capacitive charge	V _R = 400 V	15.2	nC
Ci	C _i Total capacitance	$V_R = 0 \text{ V}, T_c = 25 \text{ °C}, F = 1 \text{ MHz}$	270	рF
Oj Total Capacitance		$V_R = 300 \text{ V}, T_c = 25 \text{ °C}, F = 1 \text{ MHz}$	29	ρι

^{1.} Most accurate value for the capacitive charge: $_{Q_{cj} = \int_0^{V_{CUT}} c_j(v_R).dv_R}$

Characteristics STPSC6C065-Y

Figure 1. Forward voltage drop versus forward current (typical values, low level)

12

Pulse test: tp = 500 µs

T = 100 °C

T = 175 °C

T = 175 °C

Figure 2. Forward voltage drop versus forward current (typical values, high level) Pulse test: t_p = 500 μ 50 40 30 T = 100 °C 20 10 0 0.0 1.0 2.0 3.0 4.0 5.0 6.0 7.0 8.0

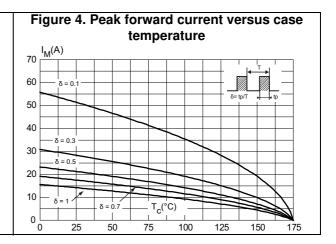
Figure 3. Reverse leakage current versus reverse voltage applied (typical values)

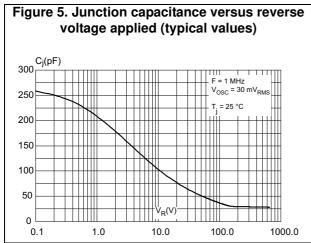
1.E+02
1.E+01
1.E-01
1.E-02
1.E-03
1.E-04
0 50 100 150 200 250 300 350 400 450 500 550 600 650

1.5

2.0

0.5





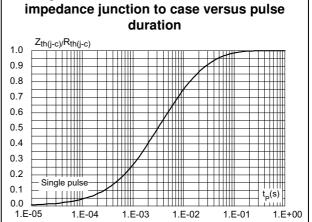


Figure 6. Relative variation of thermal

STPSC6C065-Y Characteristics

t_p(s)

1.E-02

1.E-03

Figure 7. Non-repetitive peak surge forward current versus pulse duration (sinusoidal waveform)

1.E+03

T_a = 125 °C

T_a = 125 °C

1.E-04

reverse voltage applied (typical values) Q_{Cj}(nC) 16 12 10 8 6 4 2 $V_{R}(V)$ 0 0 50 100 150 200 250 300 350 400

Figure 8. Total capacitive charges versus

57/

1.E+01

1.E-05

Package information STPSC6C065-Y

2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: *www.st.com*. ECOPACK[®] is an ST trademark.

• Epoxy meets UL94, V0

• Cooling method: by conduction (C)

• Recommended torque value: 0.55 N·m

• Maximum torque value: 0.7 N.m

2.1 TO-220AC package information

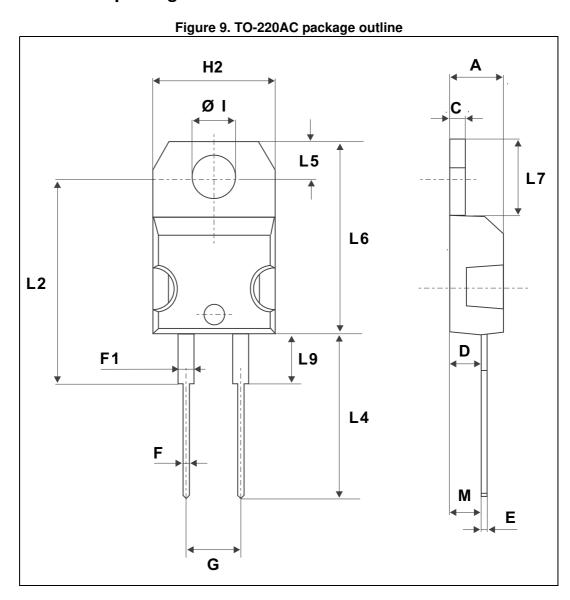


Table 6. TO-220AC package mechanical data

			Dimer	nsions		
Ref.	Millimeters			Inches		
	Min.	Тур.	Max.	Min.	Тур.	Max.
Α	4.40		4.60	0.173		0.181
С	1.23		1.32	0.048		0.051
D	2.40		2.72	0.094		0.107
E	0.49		0.70	0.019		0.027
F	0.61		0.88	0.024		0.034
F1	1.14		1.70	0.044		0.066
G	4.95		5.15	0.194		0.202
H2	10.00		10.40	0.393		0.409
L2		16.40 typ.			0.645 typ.	
L4	13.00		14.00	0.511		0.551
L5	2.65		2.95	0.104		0.116
L6	15.25		15.75	0.600		0.620
L7	6.20		6.60	0.244		0.259
L9	3.50		3.93	0.137		0.154
М		2.6 typ.			0.102 typ.	
Diam. I	3.75		3.85	0.147		0.151

Ordering information STPSC6C065-Y

3 Ordering information

Table 7. Ordering information

Order code	Marking	Package Weight		Base qty.	Delivery mode	
STPSC6C065DY	PSC6C065DY	TO-220AC	1.86 g	50	Tube	

4 Revision history

Table 8. Document revision history

Date	Revision	Changes	
13-Jan-2015	1	First issue.	
13-Dec-2016	2	Updated Table 4.	

IMPORTANT NOTICE - PLEASE READ CAREFULLY

STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, enhancements, modifications, and improvements to ST products and/or to this document at any time without notice. Purchasers should obtain the latest relevant information on ST products before placing orders. ST products are sold pursuant to ST's terms and conditions of sale in place at the time of order acknowledgement.

Purchasers are solely responsible for the choice, selection, and use of ST products and ST assumes no liability for application assistance or the design of Purchasers' products.

No license, express or implied, to any intellectual property right is granted by ST herein.

Resale of ST products with provisions different from the information set forth herein shall void any warranty granted by ST for such product.

ST and the ST logo are trademarks of ST. All other product or service names are the property of their respective owners.

Information in this document supersedes and replaces information previously supplied in any prior versions of this document.

© 2016 STMicroelectronics - All rights reserved

